NTS12120MFS, NRVTS12120MFS

Very Low Forward Voltage **Trench-based Schottky Rectifier**

Features

- Fine Lithography Trench-based Schottky Technology for Very Low Forward Voltage and Low Leakage
- Fast Switching with Exceptional Temperature Stability
- Low Power Loss and Lower Operating Temperature
- Higher Efficiency for Achieving Regulatory Compliance
- Low Thermal Resistance
- High Surge Capability
- NRV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These are Pb-Free and Halide-Free Devices

Typical Applications

- Switching Power Supplies including Notebook / Netbook Adapters, ATX and Flat Panel Display
- High Frequency and DC–DC Converters
- Freewheeling and OR-ing diodes
- Reverse Battery Protection
- LED Lighting
- Instrumentation

Mechanical Characteristics:

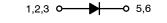
- Case: Epoxy, Molded
- Epoxy Meets Flammability Rating UL 94–0 @ 0.125 in.
- Lead Finish: 100% Matte Sn (Tin)
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Device Meets MSL 1 Requirements

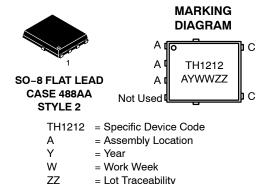


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TRENCH SCHOTTKY RECTIFIERS **12 AMPERES 120 VOLTS**





= Lot Traceability

ORDERING INFORMATION

Device	Package	Shipping†
NTS12120MFST1G	SO-8 FL (Pb-Free)	1500 / Tape & Reel
NTS12120MFST3G	SO-8 FL (Pb-Free)	5000 / Tape & Reel
NRVTS12120MFST1G	SO-8 FL (Pb-Free)	1500 / Tape & Reel
NRVTS12120MFST3G	SO-8 FL (Pb-Free)	5000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

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MAXIMUM RATINGS

Rating	Symbol	Value	Unit	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	120	V	
Average Rectified Forward Current (Rated V_R , T_C = 138°C)	I _{F(AV)}	12	A	
Peak Repetitive Forward Current, (Rated V_R , Square Wave, 20 kHz, T_C = 136°C)	I _{FRM}	24	A	
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I _{FSM}	200	A	
Storage Temperature Range	T _{stg}	-65 to +150	°C	
Operating Junction Temperature	TJ	-55 to +150	°C	
Unclamped Inductive Switching Energy (10 mH Inductor, Non-repetitive)	E _{AS}	100	mJ	
ESD Rating (Human Body Model)		3B		
ESD Rating (Machine Model)		M4		

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Тур	Max	Unit
Thermal Resistance, Junction-to-Case, Steady State (Assumes 600 mm ² 1 oz. copper bond pad, on a FR4 board)	$R_{ heta JC}$	2.0	-	°C/W

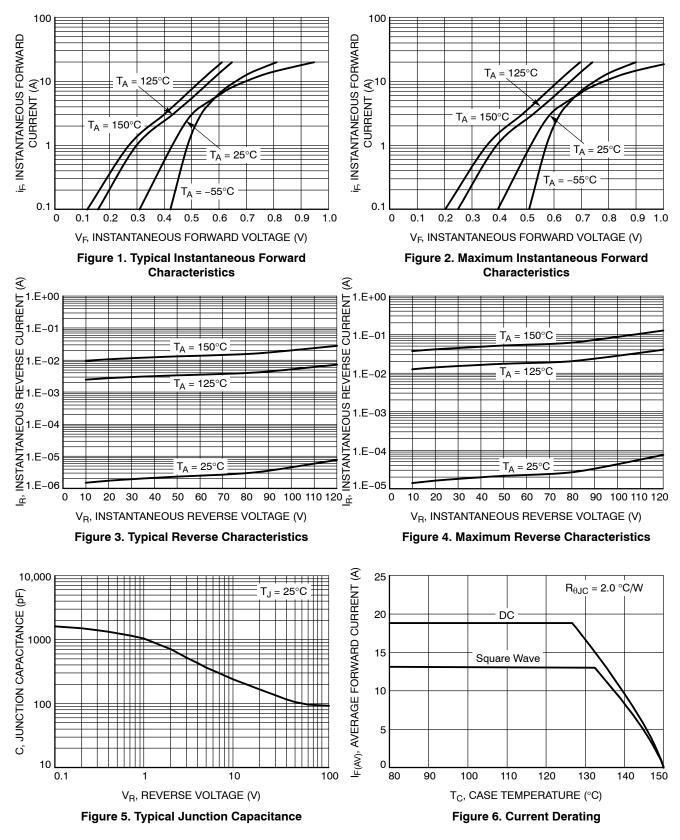
ELECTRICAL CHARACTERISTICS

Rating	Symbol	Тур	Max	Unit
Instantaneous Forward Voltage (Note 1)	VF			V
$(I_{F} = 6 \text{ A}, T_{J} = 25^{\circ}\text{C})$		0.587	-	
(I _F = 12 A, T _J = 25°C)		0.63	0.83	
(I _F = 6 A, T _{.1} = 125°C)		0.510	-	
$(I_F = 12 \text{ A}, T_J = 125^{\circ}\text{C})$		0.587	0.68	
Instantaneous Reverse Current (Note 1)	I _R			
(V _R = 90 V, T _J = 25°C)		3.4	_	μΑ
(Rated dc Voltage, $T_J = 25^{\circ}C$)		14.5	75	μΑ
(V _B = 90 V, T _J = 125°C)		3.5	_	mA
(Rated dc Voltage, $T_J = 125^{\circ}C$)		9.2	40	mA

1. Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.

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TYPICAL CHARACTERISTICS

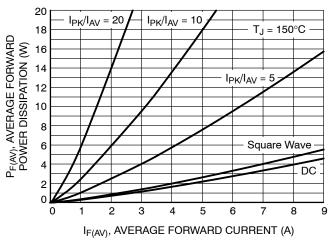
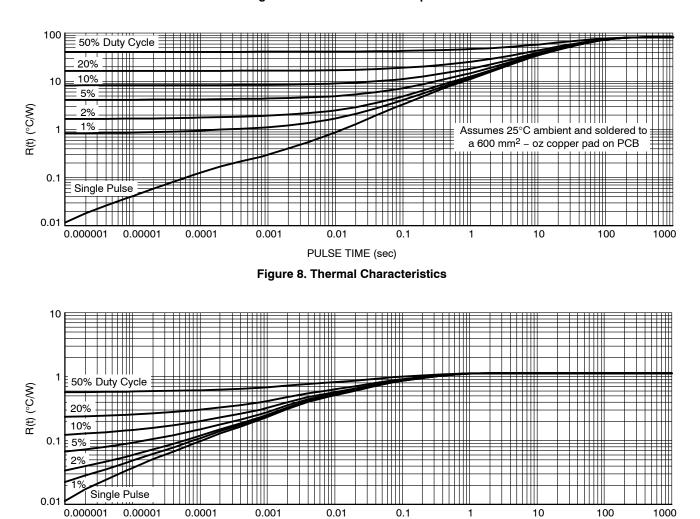


Figure 7. Forward Power Dissipation



PULSE TIME (sec)
Figure 9. Typical Transient Thermal Response Characteristics, Junction-to-Case





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